



60V 175°C N-CHANNEL ENHANCEMENT MODE MOSFET PowerDI5060-8

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _C = +25°C
	23mΩ @ V _{GS} = 10V	55A
60V	28mΩ @ V _{GS} = 4.5V	48A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}), yet maintain superior switching performance, making it ideal for high-efficiency power management applications.

Applications

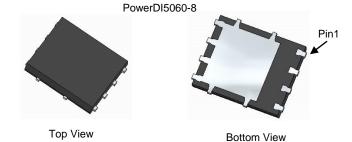
- Driving Solenoids
- Driving Relays
- Power Management Functions

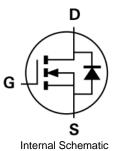
Features

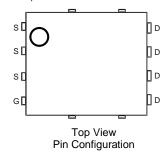
- Rated to +175°C Ideal for High Ambient Temperature Environments
- 100% Unclamped Inductive Switching Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)} Minimizes On-State Losses
- Low Input Capacitance
- · Fast Switching Speed
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- An Automotive-Compliant Part is Available Under Separate Data Sheet (<u>DMNH6021SPSQ</u>)

Mechanical Data

- Case: PowerDI[®]5060-8
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Weight: 0.097 grams (Approximate)







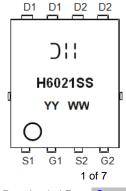
Ordering Information (Note 4)

Part Number	Case	Packaging
DMNH6021SPS-13	PowerDI5060-8	2,500/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



⊃¦¦ = Manufacturer's Marking H6021SS = Product Type Marking Code YYWW = Date Code Marking YY = Year (ex: 16 = 2016) WW = Week (01 - 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Drain-Source Voltage		V_{DSS}	60	V
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current, V _{GS} = 10V (Note 7)	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I _D	55 39	А
Maximum Continuous Body Diode Forward Current (Note 7)		I _S	55	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)		I _{DM}	88	Α
Avalanche Current, L = 0.1mH (Note 8)		I _{AS}	35	Α
Avalanche Energy, L = 0.1mH (Note 8)		E _{AS}	64	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)	$T_A = +25^{\circ}C$	P_{D}	1.6	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	96	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	P_{D}	3.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	50	°C/W
Total Power Dissipation (Note 7)	T _C = +25°C	P_D	53	W
Thermal Resistance, Junction to Case (Note 7)		$R_{\theta JC}$	1.5	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +175	°C

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

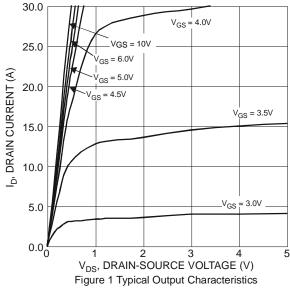
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 9)							
Drain-Source Breakdown Voltage	BV _{DSS}	60	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	1	μA	$V_{DS} = 60V$, $V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 9)							
Gate Threshold Voltage	V _{GS(TH)}	1	_	3	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	D-s/s/	_	12	23	mΩ	$V_{GS} = 10V, I_D = 12A$	
Static Dialii-Source Off-Resistance	R _{DS(ON)}	_	18	28	11122	$V_{GS} = 4.5V, I_D = 12A$	
Diode Forward Voltage	V_{SD}	_	0.75	1.2	V	$V_{GS} = 0V, I_{S} = 20A$	
DYNAMIC CHARACTERISTICS (Note 10)							
Input Capacitance	C _{ISS}	_	1,016	_		V _{DS} = 30V, V _{GS} = 0V, f = 1MHz	
Output Capacitance	Coss	_	153	_	pF		
Reverse Transfer Capacitance	C _{RSS}	_	76.8	_			
Gate Resistance	R_{G}	_	2.5	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$	
Total Gate Charge (V _{GS} = 4.5V)	Q_{G}	_	9.5	_		$V_{DS} = 30V, I_D = 20A$	
Total Gate Charge (V _{GS} = 10V)	Q_{G}	_	19.7	_	nC		
Gate-Source Charge	Q _{GS}	_	3.6	_	IIC		
Gate-Drain Charge	Q_{GD}	_	4.8	_			
Turn-On Delay Time	t _{D(ON)}	_	4.2	_		$V_{DD} = 30V, V_{GS} = 10V,$ $I_{D} = 10A, R_{G} = 4.7\Omega,$	
Turn-On Rise Time	t _R	_	13	_	ns		
Turn-Off Delay Time	t _{D(OFF)}	_	27.5	_	ns		
Turn-Off Fall Time	t _F	_	15.3	_			
Body Diode Reverse Recovery Time	t _{RR}	_	20.8	_	ns	1 200 4:/4+ 4000/	
Body Diode Reverse Recovery Charge	Q _{RR}	_	13.9	_	$_{\rm nC}$ I _F = 20A, di/dt = 100A/µs		

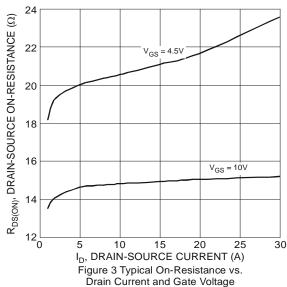
Notes:

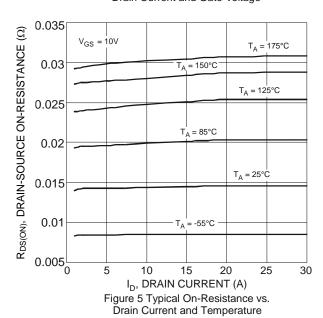
- 5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.
- 7. Thermal resistance from junction to soldering point (on the exposed drain pad).
- 8. I_{AS} and E_{AS} rating are based on low frequency and duty cycles to keep T_J = +25°C. 9. Short duration pulse test used to minimize self-heating effect. 10. Guaranteed by design. Not subject to product testing.

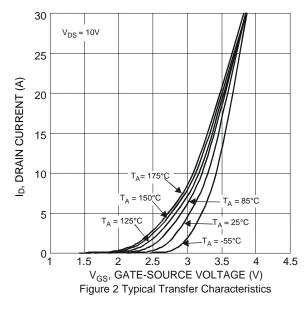
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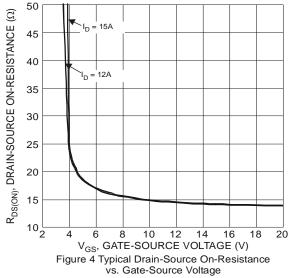


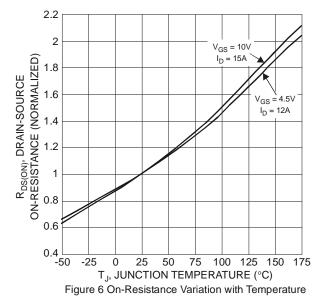






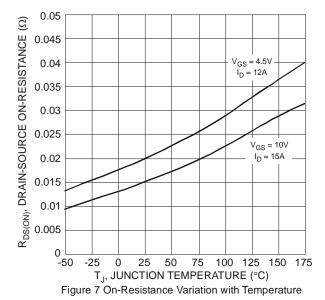


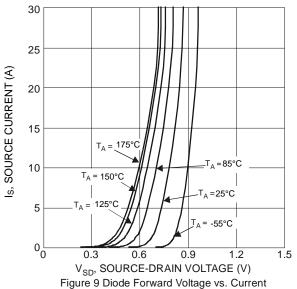


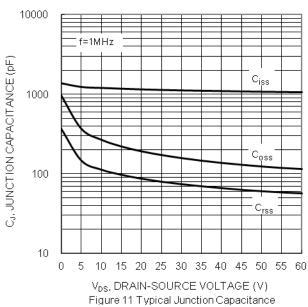


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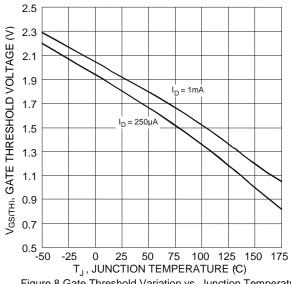
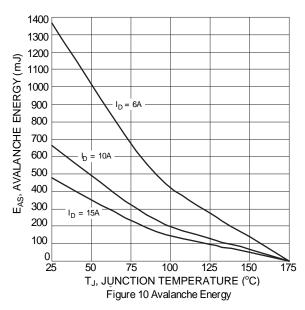
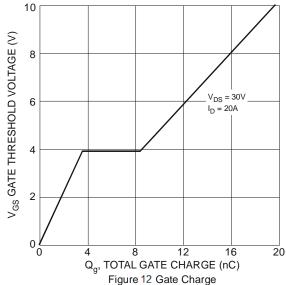


Figure 8 Gate Threshold Variation vs. Junction Temperature







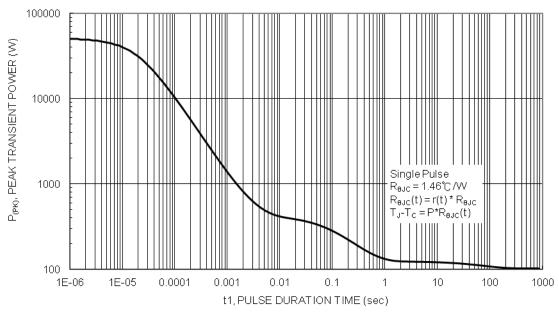


Figure 13 Single Pulse Maximum Power Dissipation

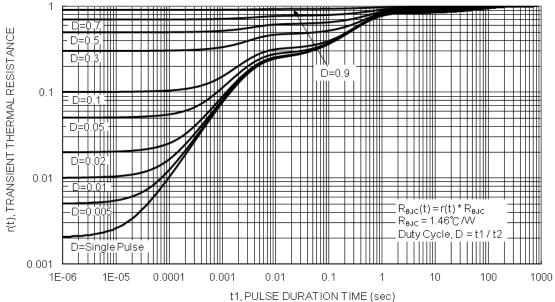


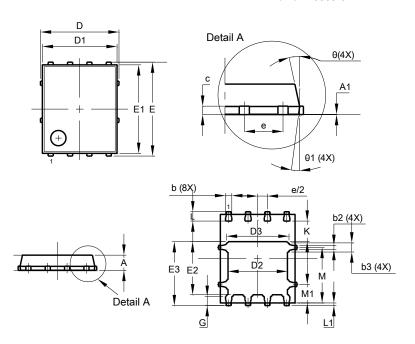
Figure 14 Transient Thermal Resistance



Package Outline

Please see http://www.diodes.com/package-outlines.html for the latest version.

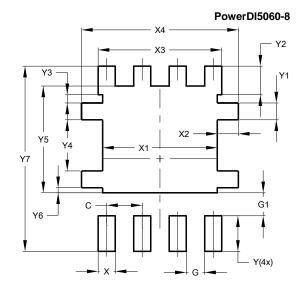
PowerDI5060-8



PowerDI5060-8					
Dim	Min	Max	Тур		
Α	0.90	1.10	1.00		
A1	0.00	0.05	-		
b	0.33	0.51	0.41		
b2	0.200	0.350	0.273		
b3	0.40	0.80	0.60		
С	0.230	0.330	0.277		
D	į.	5.15 BSC	;		
D1	4.70	5.10	4.90		
D2	3.70	4.10	3.90		
D3	3.90	4.30	4.10		
Е	(6.15 BSC	;		
E1	5.60	6.00	5.80		
E2	3.28	3.68	3.48		
E3	3.99	4.39	4.19		
е	•	1.27 BSC	;		
G	0.51	0.71	0.61		
K	0.51	-	_		
L	0.51	0.71	0.61		
L1	0.100	0.200	0.175		
М	3.235	4.035	3.635		
M1	1.00	1.40	1.21		
Θ	10°	12°	11°		
Θ1	6°	8°	7°		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)		
С	1.270		
G	0.660		
G1	0.820		
Х	0.610		
X1	4.100		
X2	0.755		
Х3	4.420		
X4	5.610		
Υ	1.270		
Y1	0.600		
Y2	1.020		
Y3	0.295		
Y4	1.825		
Y5	3.810		
Y6	0.180		
Y7	6.610		



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